

40V N-Channel Enhancement Mode MOSFET

Voltage 4

40 V

Current

180 A

Features

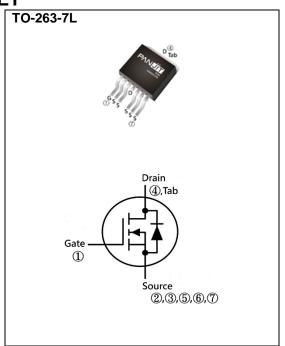
- RDS(ON), VGS@10V, ID@90A<1.88m Ω
- RDS(ON), VGS@7V, ID@50A<2.4mΩ
- Excellent FOM
- Standard Level Drive
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: TO-263-7L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 1.54 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS | |
|---|-----------------------|----------------------------------|---------|-------|--|
| Drain-Source Voltage | | V_{DS} | 40 | V | |
| Gate-Source Voltage | | V _{GS} | ±20 | v | |
| Continuous Drain Current(Note 3) | Tc=25°C | | 180 | | |
| | T _C =100°C | I _D | 180 | Α | |
| Pulsed Drain Current(Note 1) | T _C =25°C | I _{DM} | 630 | | |
| Power Dissipation | Tc=25°C | D- | 250 | W | |
| | T _C =100°C | Po | 125 | | |
| Continuous Drain Current(Note 4) | T _A =25°C | | 33 | Α | |
| | T _A =70°C | I _D | 28 | | |
| Power Dissipation | T _A =25°C | P _D | 3.8 | W | |
| | T _A =70°C | PD | 2.6 | | |
| Single Pulse Avalanche Current(Note 5) | | las | 28.5 | Α | |
| Single Pulse Avalanche Energy ^(Note 5) | | Eas | 415 | mJ | |
| Operating Junction and Storage Temperature Range | | T _J ,T _{STG} | -55~175 | °C | |
| Thermal Resistance ^(Note 4) | Junction to Case | R _{θJC} | 0.6 | °C/W | |
| | Junction to Ambient | R _{θJA} | 40 | | |



Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS | |
|----------------------------------|---------------------|---|------|------|------|--------|--|
| Static | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V_{DSS} $V_{GS}=0V$, $I_{D}=250uA$ | | - | - | \ \ | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =50uA | 2 | 2.9 | 3.5 | V | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =10V, I _D =90A | i | 1.51 | 1.88 | | |
| | | V _{GS} =7V, I _D =50A | | 1.83 | 2.4 | mΩ | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =40V, V _{GS} =0V | - | - | 1 | uA | |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA | |
| Dynamic ^(Note 6) | | | | | | | |
| Total Gate Charge | Q_g | \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | 1 | 63 | 82 | nC | |
| Gate-Source Charge | Q_{gs} | V _{DS} =32V, I _D =90A, | i | 19 | - | | |
| Gate-Drain Charge | Q_{gd} | V _{GS} =10V | i | 11 | - | | |
| Input Capacitance | Ciss | \\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | - | 4691 | 6098 | pF | |
| Output Capacitance | Coss | V _{DS} =25V, V _{GS} =0V, f=1MHz | - | 979 | 1371 | | |
| Reverse Transfer Capacitance | Crss | I=IIVIMZ | - | 80 | 140 | | |
| Gate resistance | Rg | f=1MHz | - | 0.6 | - | Ω | |
| Turn-On Delay Time | td _(on) | \/ 00\/ L 00A | - | 21 | - | | |
| Turn-On Rise Time | tr | V _{DS} =32V, I _D =90A, | - | 22 | - | ns | |
| Turn-Off Delay Time | td _(off) | $V_{GS}=10V, R_{G}=3\Omega$ | - | 49 | - | | |
| Turn-Off Fall Time | tf | (Note 2) | - | 15 | - | | |
| Drain-Source Diode | | | | | | | |
| Diode Forward Current | Is | Tc=25°C | 1 | - | 180 | Α | |
| Pulsed Diode Forward Current | I _{SM} | 1c=25 C | i | - | 630 | | |
| Diode Forward Voltage | V _{SD} | Is=20A, V _{GS} =0V | ı | 0.79 | 1.3 | V | |
| Reverse Recovery Time | Trr | V _{DD} =32V,V _{GS} =0V | i | 44 | - | ns | |
| Reverse Recovery Charge | Qrr | I _S =20A,dI _S /dt=100A/us | - | 27 | - | nC | |

NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an R_{BJC}=0.6°C/W, Package limited 180A.
- 4. R_{BJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. Eas is calculated based on the condition of L=1mH, Ias=28.8A, V_{DD}=30V, V_G=10V. 100% test at L=0.5mH, Ias=28.5A in production.
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

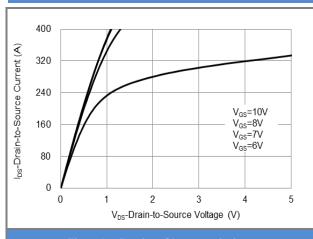


Fig.1 On-Region Characteristics

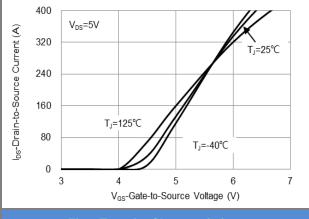


Fig.2 Transfer Characteristics

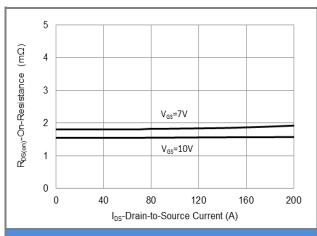


Fig.3 On-Resistance vs. Drain Current

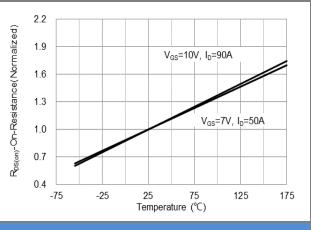


Fig.4 On-Resistance vs. Junction temperature

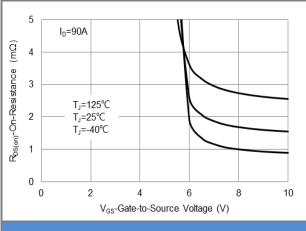
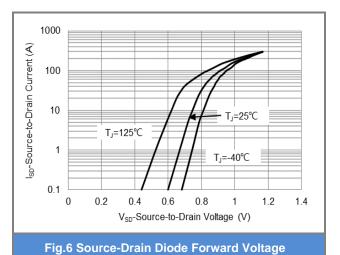


Fig.5 On-Resistance Variation with V_{GS}





TYPICAL CHARACTERISTIC CURVES

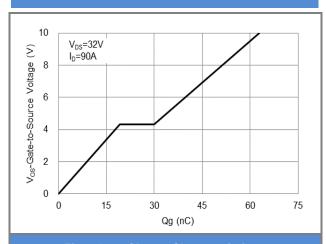


Fig.7 Gate-Charge Characteristics

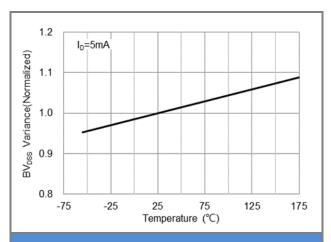


Fig.8 Breakdown Voltage Variation vs. Temperature

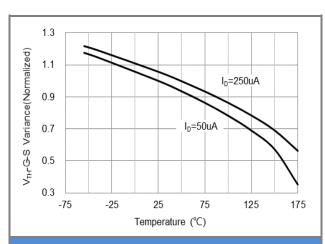


Fig.9 Threshold Voltage Variation with Temperature

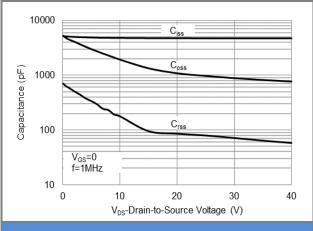
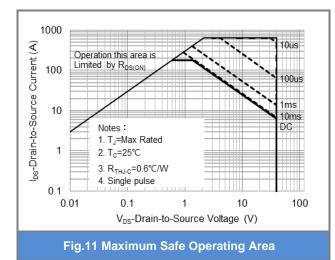


Fig.10 Capacitance vs. Drain-Source Voltage



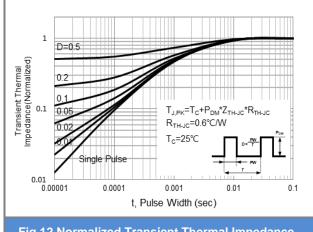


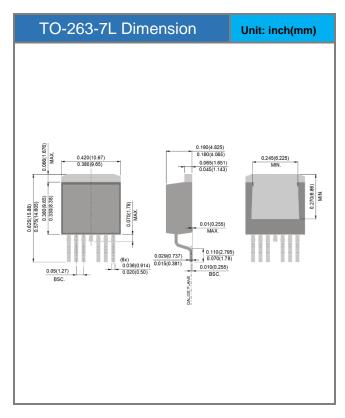
Fig.12 Normalized Transient Thermal Impedance

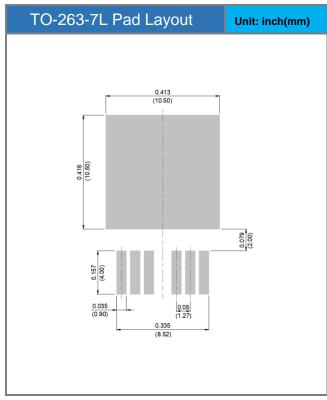


Product and Packing Information

| Part No. | Package Type | Packing Type | Marking | |
|----------------|--------------|--------------------|---------|--|
| PJB180N04V7-AU | TO-263-7L | 800 pcs / 13" reel | 180N04V | |

Packaging Information & Mounting Pad Layout







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